NPN Silicon Planar Epitaxial Transistor

This NPN Silicon Epitaxial transistor is designed for use in linear and switching applications. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

Features

- PNP Complement is PZT2907AT1
- The SOT-223 Package Can be Soldered Using Wave or Reflow
- SOT-223 Package Ensures Level Mounting, Resulting in Improved Thermal Conduction, and Allows Visual Inspection of Soldered
- The Formed Leads Absorb Thermal Stress During Soldering, Eliminating the Possibility of Damage to the Die
- Available in 12 mm Tape and Reel
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CBO}	75	Vdc
Emitter-Base Voltage (Open Collector)	V _{EBO}	6.0	Vdc
Collector Current	I _C	600	mAdc
Total Power Dissipation up to T _A = 25°C (Note 1)	P _D	1.5	W
Storage Temperature Range	T _{stg}	- 65 to +150	°C
Junction Temperature	T _J	150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Device mounted on an epoxy printed circuit board 1.575 inches x 1.575 inches x 0.059 inches; mounting pad for the collector lead min. 0.93 inches².

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625" from case Time in Solder Bath	T _L	260 10	°C Sec



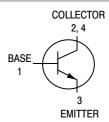
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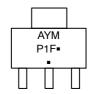
SOT-223 PACKAGE NPN SILICON TRANSISTOR SURFACE MOUNT



SOT-223 (TO-261) CASE 318E-04 STYLE 1



MARKING DIAGRAM



Assembly Location

= Year = Month Code M = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
PZT2222AT1G	SOT-223 (Pb-Free)	1,000 Tape & Reel
SPZT2222AT1G	SOT-223 (Pb-Free)	1,000 Tape & Reel
PZT2222AT3G	SOT-223 (Pb-Free)	4,000 Tape & Reel

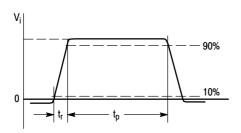
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERIST	ics	<u> </u>			
Collector-Emitter Brea	akdown Voltage (I _C = 10 mAdc, I _B = 0)	V _{(BR)CEO}	40	_	Vdc
Collector-Base Break	down Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	75	-	Vdc
Emitter-Base Breakdo	own Voltage (I _E = 10 μAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Base-Emitter Cutoff C	Current (V _{CE} = 60 Vdc, V _{BE} = - 3.0 Vdc)	I _{BEX}	-	20	nAdc
Collector-Emitter Cut	off Current (V _{CE} = 60 Vdc, V _{BE} = - 3.0 Vdc)	I _{CEX}	-	10	nAdc
Emitter-Base Cutoff C	Current (V _{EB} = 3.0 Vdc, I _C = 0)	I _{EBO}	_	100	nAdc
Collector-Base Cutoff	Current	I _{CBO}			
$(V_{CB} = 60 \text{ Vdc}, I_{E} =$			-	10	nAdd
(V _{CB} = 60 Vdc, I _E =	,		_	10	μAdo
ON CHARACTERISTIC	CS				I
DC Current Gain (I _C = 0.1 mAdc, V _{CE}	10 Vdc)	h _{FE}	35	_	_
$(I_C = 1.0 \text{ mAdc}, V_{CE})$			50	_	
$(I_C = 10 \text{ mAdc}, V_{CE})$			70	_	
	$= 10 \text{ Vdc}, T_A = -55^{\circ}\text{C})$		35	-	
(I _C = 150 mAdc, V _C			100	300	
$(I_C = 150 \text{ mAdc}, V_C)$ $(I_C = 500 \text{ mAdc}, V_C)$			50 40	_	
Collector-Emitter Satu	<u> </u>	V _{CE(sat)}			Vdc
$(I_C = 150 \text{ mAdc}, I_B =$	= 15 mAdc)	OL(out)	_	0.3	
$(I_C = 500 \text{ mAdc}, I_B =$	= 50 mAdc)		-	1.0	
Base-Emitter Saturati	on Voltages	V _{BE(sat)}			Vdc
$(I_C = 150 \text{ mAdc}, I_B =$	= 15 mAdc)	22(04.)	0.6	1.2	
$(I_C = 500 \text{ mAdc}, I_B =$	= 50 mAdc)		-	2.0	
Input Impedance		h _{ie}			kΩ
	1.0 mAdc, f = 1.0 kHz)		2.0	8.0	
(V _{CE} = 10 Vdc, I _C =	10 mAdc, f = 1.0 kHz)		0.25	1.25	
Voltage Feedback Ra		h _{re}			_
	1.0 mAdc, $f = 1.0 \text{ kHz}$)		-	8.0x10 ⁻⁴	
(V _{CE} = 10 Vdc, I _C =	10 mAdc, f = 1.0 kHz)		-	4.0x10 ⁻⁴	
Small-Signal Current		h _{fe}			_
	1.0 mAdc, f = 1.0 kHz)		50	300	
	10 mAdc, f = 1.0 kHz)		75	375	
Output Admittance		h _{oe}			μmho
,	1.0 mAdc, f = 1.0 kHz) 10 mAdc, f = 1.0 kHz)		5.0 25	35 200	
	0 Vdc, I _C = 100 μAdc, f = 1.0 kHz)	F	-	4.0	dB
		'		4.0	QD.
DYNAMIC CHARACTI		,		1	
Current-Gain - Band	width Product = 20 Vdc, f = 100 MHz)	f⊤	300	_	MHz
Output Capacitance (C _c	_	8.0	pF	
	EB = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _e	_	25	рF
SWITCHING TIMES (T				20	Pi
	$V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc},$	+.		10	nc
i,	V _{CC} = 30 Vdc, I _C = 150 madc, _{B(on)} = 15 mAdc, V _{EB(off)} = 0.5 Vdc)	t _d	-		ns
Rise Time F	igure 1	t _r	-	25	
	$V_{CC} = 30 \text{ Vdc}, I_C = 150 \text{ mAdc},$ $I_{S(on)} = I_{B(off)} = 15 \text{ mAdc}$	t _s	_	225	ns
	B(on) = 1B(off) = 15 MACC) Figure 2	t _f	-	60	
	-		1		l



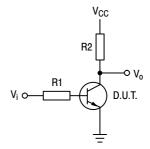


Figure 1. Input Waveform and Test Circuit for Determining Delay Time and Rise Time

 $\mbox{V}_{\mbox{\scriptsize i}}$ = - 0.5 V to +9.9 V, $\mbox{V}_{\mbox{\scriptsize CC}}$ = +30 V, R1 = 619 $\Omega,$ R2 = 200 $\Omega.$

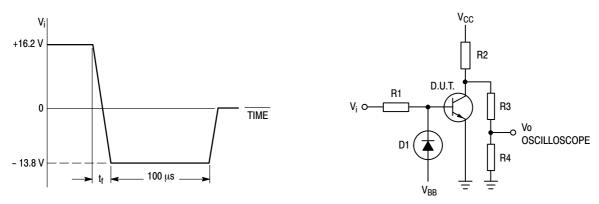
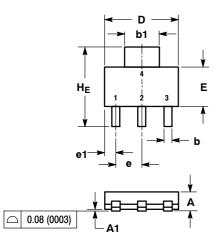


Figure 2. Input Waveform and Test Circuit for Determining Storage Time and Fall Time

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 **ISSUE N**





DIMENSIONING AND TOLERANCING PER ASME Y14.5M, NTROLLING DIMENSION: INCH

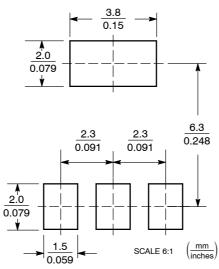
	CONTROLLING DIMENSION: INCH.					
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
A	0°	_	10°	0°	_	10°

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER

4 COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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